## NSN 5962-00-007-7893

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View Online at https://aerobasegroup.com/nsn/5962-00-007-7893
Body Length:
Between 1.200 inches and 1.290 inches
Body Width:
Between 0.515 inches and 0.525 inches
Body Height:
Between 0.130 inches and 0.180 inches
Maximum Power Dissipation Rating:
625.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and w/enable and negative outputs and positive outputs and programmable and programmed and
w/storage
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-8.0 volts power source and 12.3 volts power source
Time Rating Per Chacteristic:
650.00 nanoseconds propagation delay time, low to high level output and 650.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
05869-717382-3 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:

Demilitarization: Yes - demil/mli

**Unit Of Measure:** 

N/a

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